

APT1608SURCK-AMT

1.6 x 0.8 mm SMD Chip LED Lamp



DESCRIPTIONS

- The Hyper Red source color devices are made with AIGaInP on GaAs substrate Light Emitting Diode
- · Electrostatic discharge and power surge could damage the LEDs
- · It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 1.6 mm x 0.8 mm SMD LED, 0.75 mm thickness
- Low power consumption
- Wide viewing angle
- · Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- RoHS compliant

APPLICATIONS

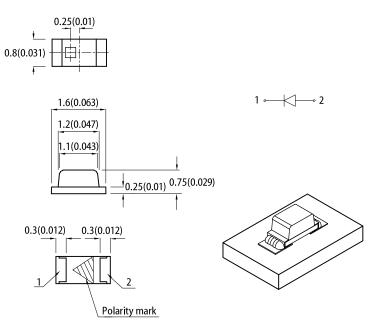
- Traffic signaling
- · Backlighting (illuminated advertising, general lighting)
- · Interior and exterior automotive lighting
- Substitution of micro incandescent lamps
- Reading lamps
- Signal and symbol luminaire for orientation
- Marker lights (e.g. Steps, exit ways, etc)
- · Decorative and entertainment lighting
- · Indoor and outdoor commercial and residential architectural lighting

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices



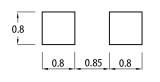
PACKAGE DIMENSIONS

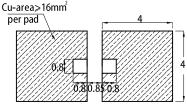


RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)

Pad Design for Improved Heat Dissipation





🕅 Solder resist

*55

*80

*80

*120

Notes

All dimensions are in millimeters (inches).

Tolerance is ±0.1(0.004") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to

change without prior notice. The device has a single mounting surface. The device must be mounted according to the specifications 4.

*H

*M

SELECTION GUIDE lv (mcd) @ 20mA [2] Viewing Angle^[1] **Emitting Color** Part Number Lens Type (Material) Code. Min. Max. 201/2 120 200 Ν Р 200 300 Q 300 400 Hyper Red (AlGaInP) *F *40 APT1608SURCK-AMT Water Clear *20 120° *55 *G *40

Notes

- 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Luminous intensity / luminous flux: +/-15%.
 * Luminous intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Devenueári		Value			1114		
Parameter	Symbol	Emitting Color	Min.	Тур.	Max.	Unit	
Wavelength at Peak Emission I_F = 20mA	λ_{peak}	Hyper Red	-	645	-	nm	
Dominant Wavelength I _F = 20mA	λ_{dom} ^[1]	Hyper Red	620		640	nm	
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Hyper Red	-	28	-	nm	
Capacitance	С	Hyper Red	-	35	-	pF	
Forward Voltage $I_F = 20mA$	V _F ^[2]	Hyper Red	-	1.95	2.5	V	
Reverse Current (V _R = 5V)	I _R	Hyper Red	-	-	10	uA	
Temperature Coefficient of λ_{peak} I_F = 20mA, -10°C $\leq T \leq$ 100°C	TC _{λpeak}	Hyper Red	-	0.14	-	nm/°C	
Temperature Coefficient of λ_{dom} I _F = 20mA, -10°C \leq T \leq 100°C	TC _{λdom}	Hyper Red	-	0.05	-	nm/°C	
Temperature Coefficient of V _F I _F = 20mA, -10°C \leq T \leq 100°C	TCv	Hyper Red	-	-1.9	-	mV/°C	

Notes:

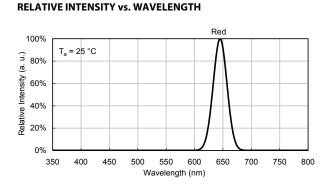
The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd : ±1nm.)
 Forward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

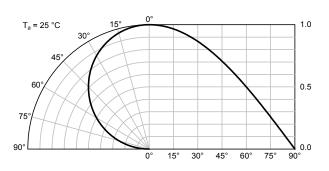
Parameter	Symbol	Value	Unit
Power Dissipation	P _D	75	mW
Reverse Voltage	V _R	5	V
Junction Temperature	Tj	115	°C
Operating Temperature	T _{op}	-40 to +100	°C
Storage Temperature	T _{stg}	-40 to +115	°C
DC Forward Current	I _F	30	mA
Peak Forward Current	I _{FM} ^[1]	185	mA
Electrostatic Discharge Threshold (HBM)	-	3000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	570	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	420	°C/W

Notes: 1. /1/10 Duty Cycle, 0.1ms Pulse Width. 2. R_{in, Ja}, R_{in, JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

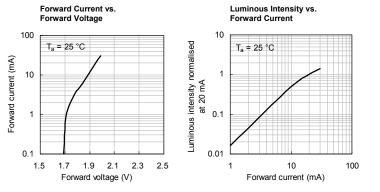
TECHNICAL DATA

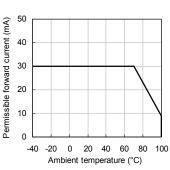


SPATIAL DISTRIBUTION



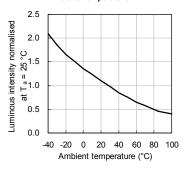
HYPER RED



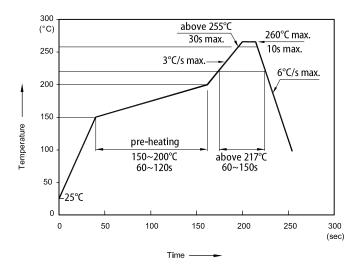


Forward Current Derating Curve

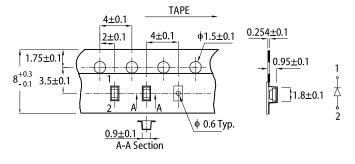




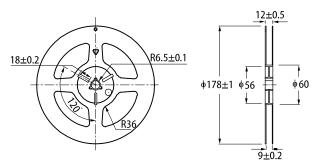
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units : mm)



REEL DIMENSION (units : mm)

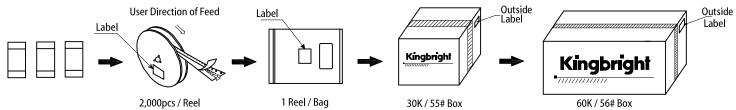


Notes:

- 1. Don't cause stress to the LEDs while it is exposed to high temperature.
- The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

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PACKING & LABEL SPECIFICATIONS







RELIABILITY TEST ITEMS AND CONDITIONS

The reliability of products shall be satisfied with items listed below

LOT TOLERANCE PERCENT DEFECTIVE (LTPD): 10%

No.	Test Item	Standards	Test Condition	Test Times / Cycles	Number of Damaged
1	Continuous operating test	-	T_a = 25°C, I_F = maximum rated current *	1,000 h	0 / 22
2	High Temp. operating test	EIAJ ED-4701/100(101)	T_a = 100°C, I _F = derated current at 100°C	1,000 h	0 / 22
3	Low Temp. operating test	-	T_a = -40°C, I_F = maximum rated current *	1,000 h	0 / 22
4	High temp. storage test	EIAJ ED-4701/100(201)	T _a = maximum rated storage temperature	1,000 h	0 / 22
5	Low temp. storage test	EIAJ ED-4701/100(202)	T _a = -40°C	1,000 h	0 / 22
6	High temp. & humidity storage test	EIAJ ED-4701/100(103)	T _a = 60°C, RH = 90%	1,000 h	0 / 22
7	High temp. & humidity operating test	EIAJ ED-4701/100(102)	$T_a = 60^{\circ}C$, RH = 90% I _F = derated current at 60°C	1,000 h	0 / 22
8	Soldering reliability test	EIAJ ED-4701/100(301)	Moisture soak: 30°C, 70% RH, 72h Preheat: 150~180°C (120s max.) Soldering temp: 260°C(10s)	2 times	0 / 18
9	Thermal shock operating test	-	$T_a = -40^{\circ}C(15min) \sim 100^{\circ}C(15min)$ $I_F = derated current at 100^{\circ}C$	1,000 cycles	0 / 22
10	Thermal shock test	-	T _a = -40°C(15min) ~ 100°C(15min)	1,000 cycles	0 / 22
11	Electric Static Discharge (ESD)	EIAJ ED-4701/100(304)	C = 100pF, R2 = 1.5KΩ V = 3000V	Once each Polarity	0 / 22
12	Vibration test	-	a = 196m/s ² , f = 100~2KHz, t = 48min for all xyz axes	4 times	0 / 22

*: Refer to forward current vs. derating curve diagram

CRITERIA FOR JUDGING DAMAGE

Items	Symbols	Conditions	Failure Criteria		
luminous Intensity	Ι _V	I _F = 20mA	Testing Min. Value < Spec. Min. Value x 0.5		
Forward Voltage	V _F	I _F = 20mA	Testing Max. Value ≥ Spec. Max. Value x 1.2		
Reverse Current	I _R	V _R = Maximum Rated Reverse Voltage	Testing Max. Value ≥ Spec. Max. Value x 2.5		
High temp. storage test	-	-	Occurrence of notable decoloration, deformation and cracking		

PRECAUTIONARY NOTES

1. 2.

The information included in this document reflects representative usage scenarios and is intended for technical reference only. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.

When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening 3.

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5. 6. nNotes